Dimeric Gallium Oxide and Sulfide Species Stabilized by a Sterically Encumbered β -Diketiminate Ligand

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Organo group 13 metal chalcogenides of formula (RME)_n (R = alkyl, aryl, or related group; M = Al, Ga, or In; E = O, S, Se, or $Te)^{1-22}$ can be synthesized by a variety of synthetic routes. For the organometalloxanes $(RMO)_n$, the most widely used method involves the controlled hydrolysis of metal trialkyls MR₃.^{5,6} For the heavier chalocogenides, the direct reaction of organo M(I) or M(III) precursors with the elemental chalcogens usually affords the $(RME)_n$ (E = S, Se, or Te) congeners.^{1-4,7-13,18-20} A common feature of these products is that they are oligometric, with n = 4-8 as the most common association numbers. In the lighter oxo derivatives, in particular those of aluminum, relatively high degrees of association are often found, even with fairly large organic groups such as t-Bu. Only in the case of the very large substituent -C₆H₂-2,4,6-t-Bu₃ (Mes*) was a lower degree of aggregation (4) observed in the compound (Mes*AlO)₄,¹⁴ which has an unusual Al₄O₄ ring structure instead of a three-dimensional cubane arrangement.²¹ In contrast, structurally characterized $(RGaO)_n$ cages are limited to the silvl substituted species $\{(t-Bu)_3SiGaO\}_4$ which has an almost perfectly cubic Ga₄O₄ core and an average Ga–O distance near 1.92 Å.²² It is now shown that use of the sterically encumbering β -diketiminate ligand [HC(MeCDippN)₂]⁻ (Dipp = C_6H_3 -2,6-i- Pr_2)²³ stabilizes the first dimeric galloxane derivative $[{HC(MeCDippN)_2}GaO]_2,$

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- (21) Besides (Mes*AlO)₄ (ref 14), the only other structurally characterized tetrameric group 13 metal (RMO)₄ species are {(Me₃Si)₃CInO}₄ (ref 16) and {(t-Bu)₃SiGaO}₄ (ref 22) both of which have cubane structures.
- (22) Wiberg, N.; Amelunxen, K.; Lerner, H.-W.; Nöth, H.; Ponikwar, W.; Schwenk, H. J. Organomet. Chem. 1999, 574, 246. Also, the species (t-BuGaO)₉ has been spectroscopically characterized. The data suggest that it has a structure derived from two parallel Ga₃O₃ rings linked by three GaO units (ref 4).

Table 1. Selected Bond Distances (Å) and Angles (deg) for
$[{HC(MeCDippN)_2}GaE]_2 (E = O (1), S (2))$

	1	2
Ga-E(1)	1.8536(9)	2.2511(7)
Ga-E(1A)	1.8485(9)	2.2736(7)
Ga-N(1)	1.970(1)	1.986(2)
Ga-N(2)	1.978(1)	1.983(2)
Ga(1)•••Ga(1A)	2.5989(3)	3.0127(6)
Ga-E-Ga	88.18(4)	83.49(2)
E-Ga-E	90.82(4)	96.51(2)
N-Ga-N	94.96(4)	94.01(2)

1, as well as its sulfur analogue $[{HC(MeCDippN)_2}GaS]_2$, 2. In addition, compound 1 was obtained by a facile route involving the reaction of ${HC(MeCDippN)_2}Ga:^{24}$ with N₂O.

Treatment of {HC(MeCDippN)₂}Ga: with N₂O or S₈ in toluene solution at room temperature produced compounds **1** or **2** as colorless crystals that possess low solubility in hydrocarbon solvents.²⁵ The compounds were characterized by C, H, N analysis, ¹H NMR spectroscopy, and X-ray crystallography.²⁶ The structures of **1** and **2** may be illustrated by the thermal ellipsoid plot of **1** in Figure 1. Selected bond lengths and angles are provided in Table 1. Both compounds are dimeric, which can be attributed to the large size and bidentate nature of the β -diketiminate ligands. There is a center of symmetry in the middle of their

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- (25) All manipulations were carried out under anaerobic and anhydrous conditions. A toluene solution (63 mL) of {HC(MeCDippN)₂}Ga: (0.805 g, 1.65 mmol) was added dropwise under slightly positive pressure to a septum-capped, 100 mL Schlenk tube that had been flushed with N2O and vented with a needle. A white precipitate formed immediately. Upon completion of the addition, stirring was continued for 1 h, whereupon the mixture was heated to redissolve the precipitate. Cooling to room temperature afforded the product 1 as large colorless crystals. Yield: 0.52 g, 62%. Mp: 246–249 °C. Anal. Calcd for $C_{29}H_{41}GaN_{2}O:$ C, 69.19; H, 8.21; N, 5.57. Found: C, 69.91; H, 8.34; N, 5.12. 1H NMR ($C_7D_8,$ 400 MHz): δ 7.13. 7.10 (m, 6H, aromatic H of Ar group), 4.77 (s, 1H, methane CH), 3.18 (sept, ${}^{3}J_{HH} = 7.2$ Hz, 4H, CHMe₂), 1.32 (s, 6H, CMe), 1.24 (d, ${}^{3}J_{HH} = 6.8$ Hz, 12H, CHMe₂), 1.12 (d, ${}^{3}J_{HH} = 7.2$ Hz, 12H, CHMe₂). 2: A toluene solution (50 mL) of {HC(MeCDippN)₂}Ga: (0.42 g, 0.803 mmol) was added to sulfur (0.04 g, 1.25 mmol) with rapid stirring and cooling in an ice bath. The solution was allowed to come to room temperature and stirred for a further 12 h. The resultant white precipitate was redissolved by heating. Cooling the solution to room temperature over a 2 h period produced 2 as colorless crystals. Yield: 0.15 g, 34%. Mp: decomposes slowly above 280 °C. Anal. Calcd for C₂9H₄(GaN₂S: C, 67.05; H, 7.96; N, 5.39. Found: C, 67.91; H, 7.76; N, 5.01. ¹H NMR (C₇D₈, 300 MHz): δ 7.10 (br, s, 6H, aromatic H's of Ar group), 4.73 (s, 1H, methane CH), 3.25 (sept. ${}^{3}J_{HH} = 6.9$ Hz, 4H, CHMe₂), 1.61 (s, 6H, CMe), 1.28 (d, ${}^{3}J_{HH} = 6.9$ Hz, 12H, CHMe₂), 1.10 (d, ${}^{3}J_{\rm HH} = 6.9$ Hz, 12H, CHMe₂).
- (26) Crystal data at 90 K with Mo K α ($\lambda = 0.710$ 73 Å) radiation: **1**, C₂₉H₄₁-GaN₂O, fw = 503.36, colorless parallelepipeds, a = 13.7132(7) Å, b = 13.7585(7) Å, c = 14.2230(7) Å, $\beta = 107.278(1)^{\circ}$, monoclinic, space group $P2_1/n$, V = 2562.4(2) Å³, Z = 4, $\rho_{calc} = 1.305$ Mg m⁻³, $\mu = 1.098$ mm⁻¹, R1 = 0.0285 for 6739 ($I \ge 2 \sigma(I)$) data; **2**, C₂₉H₄₁GaN₂S, fw = 519.42, colorless parallelepipeds, a = 22.4257(9) Å, b = 14.7953(6) Å, c = 16.3518(6) Å, $\beta = 90.368(1)^{\circ}$, monoclinic, space group C2/c, Z = 8, $\rho_{calc} = 1.272$ Mg m⁻³, $\mu = 1.110$ mm⁻¹, R1 = 0.0503 for 5887 ($I \ge 2 \sigma(I)$) data.

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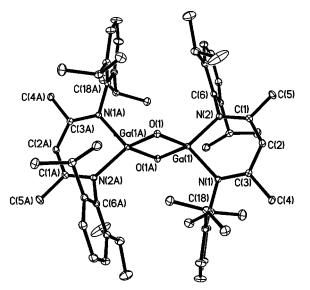


Figure 1. Thermal ellipsoid (30%) drawing of 1. H atoms are not shown.

Ga₂O₂ or Ga₂S₂ cores. The Ga₂O₂ array is almost perfectly square with angles within ca. 0.8° of 90° and Ga-O distances that differ by only 0.005 Å. The Ga····Ga separation is 2.5989(3) Å, which is just slightly longer than double the covalent radius of gallium and shorter than Ga···Ga distances of 2.7052(9)-2.7188(7) Å in {(t-Bu)₃SiGaO}₄.²² However, owing to the electronegative nature of the nitrogen and oxygen ligand atoms, the gallium center has considerable ionic character which decreases its effective radius. Thus, significant Ga…Ga interaction is probably small. The Ga-N distances are both ca. 0.07 Å shorter than the 2.054(2) Å average value seen in the Ga(I) precursor {HC(Me-CDippN)₂}Ga:.²⁴ This is most probably a result of the change in oxidation state from Ga(I) in the precursor to Ga(III) in 1.²⁷ The Ga-O distance, av 1.851(3) Å, may be compared to the 1.821(3), 1.822(3), or 1.831(4) Å observed in the low-coordinate species t-Bu₂GaOC₆H₂-2,6-t-Bu₂-4-Me,²⁸ (2,2,6,6-tetramethyl-piperidino)₂GaOPh,²⁹ or t-Bu₂GaOCPh₃³⁰ in addition to the 1.79(1) Å observed in the dimetalloxane $O{Ga(Mes^*)Mn(CO)_5}_2$ $(Mes^* = C_6H_2-2,4,6-t-Bu_3)$.³¹ All of these compounds feature

- (27) In the compounds {HC(MeCDippN)₂}GaX₂ (X = Cl or I), the Ga(III)–N distances are in the range 1.906(3)–1.948(1) Å. See: Stender, M.; Eichler, B. E.; Hardman, N. J.; Power, P. P.; Prust, J.; Noltemeyer, M.; Roesky, H. W. *Inorg. Chem.*, in press.
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three-coordinate gallium bound to two-coordinate oxygen. The slightly longer Ga-O bond in 1 can be attributed to the higher (4) coordination of the metal in this species.

The sulfur derivative 2 also has a bridged dimeric structure³² which is analogous to that of **1**. The Ga_2S_2 core is planar and has an average Ga-S bond length of 2.26(1) Å. This distance is just within the currently known range (2.20-2.27 Å) for lowcoordinate Ga-S species.^{4,33-35} Unlike the almost square core geometry in 1, the ring angle at sulfur 83.49(2)° differs considerably from the 96.51(2)° at gallium. Despite the narrower sulfur angle, the Ga····Ga separation is 3.0127(3) Å, which is similar to the Ga····Ga separation of 3.099(6) Å in (t-BuGaS)₄.² Although no dimeric gallium structures are available for comparison, the structure of the organoaluminum sulfide dimer (Mes*AlS)2 (Mes* = C_6H_2 -2,4,6-t-Bu₃) was described recently.¹⁵ It is notable that this compound shows similar angular distortions in its core in that the angle at sulfur $(A1-S-A1 = 78.09(3)^{\circ})$ is also narrower than the angle at the metal (S-AI-S = $101.91(3)^{\circ}$). In contrast, the oxygen analogue (Mes*AlO)₄ is a tetramer with a unique, planar Al₄O₄ ring structure in which the Al-O-Al angle is a wide 151.32(13)°. It was argued that the reluctance of the sulfur atom to hybridize led to narrower angles which resulted in greater steric congestion and a lower degree of aggregation for that molecule. These findings suggest that there is considerable strain in the structure of 1 and that dissociation to monomeric species featuring formal GaO multiple bonding may be possible with suitable ligand modification.³⁶

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Supporting Information Available: Two X-ray files in CIF format. This material is available free of charge via the Internet at http://pubs.acs.org.

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